



DMT6004SPS

Product Summary

BV _{DSS}	Rds(on) MAX	I _D MAX T _C = +25°C (Note 9)	
60V	3.1mΩ @ V _{GS} = 10V	100A	

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Switching
- Synchronous rectifications
- DC-DC converters

60V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Features

- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable And Robust End Application
- Low R_{DS(ON)} Minimizes Power Losses
- Low Q_g Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

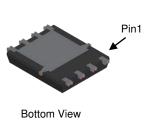


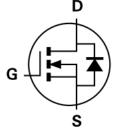
Site 2:

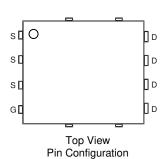
PowerDI5060-8/SWP (Type UX)



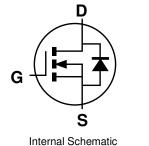
Top View

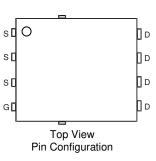






Internal Schematic





Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Fackage	Qty.	Carrier	
DMT6004SPS-13	PowerDI5060-8	2,500	Tape & Reel	
DMT6004SPS-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

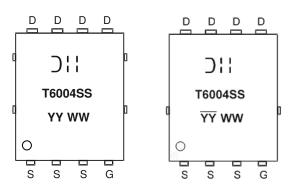
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



);; = Manufacturer's Marking T6004SS = Product Type Marking Code YYWW = Date Code Marking YY or YY = Year (ex: 23 = 2023) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	60	V		
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 5)	Steady State	$T_{A} = +25^{\circ}C$ $T_{A} = +70^{\circ}C$	ID	23 18	А
Continuous Drain Current (Notes 6 & 9) $T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$			ID	100 100	А
Maximum Continuous Body Diode Forward Current (Notes 6 & 9)			ls	100	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			ldм	400	А
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			lsм	400	А
Avalanche Current, L = 0.2mH			I _{AS}	45	A
Avalanche Energy, L = 0.2mH			E _{AS}	200	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient	Steady State	Reja	47	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	139	W
Thermal Resistance, Junction to Case		Rejc	0.9	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).

- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.

9. Package limited.

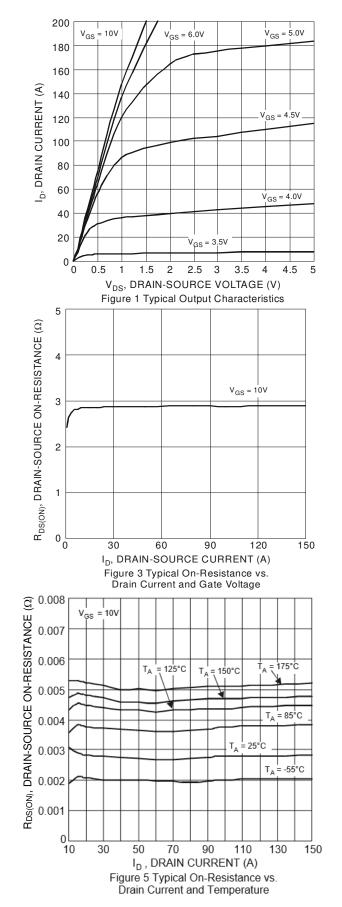


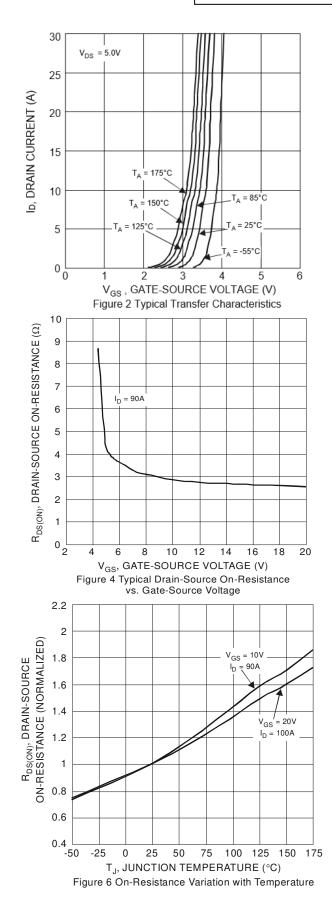
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)			1			1	
Drain-Source Breakdown Voltage	BVDSS	60	_	—	V	VGS = 0V, ID = 1mA	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	2	2.5	4	V	$V_{DS}=V_{GS},\ I_{D}=250\mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	—	—	3.1	mΩ	$V_{GS} = 10V, I_D = 50A$	
Diode Forward Voltage	V _{SD}	_	0.9	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	4,556	_		V _{DS} = 30V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	—	1,383	_	pF		
Reverse Transfer Capacitance	Crss	—	105.2	_			
Gate Resistance	Rg	_	0.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	—	95.4	_		$\label{eq:VDD} \begin{array}{l} V_{DD}=30V,\ I_{D}=90A,\\ V_{GS}=10V \end{array}$	
Gate-Source Charge	Qgs	—	21.6	_	nC		
Gate-Drain Charge	Q _{gd}	_	20.4	—			
Turn-On Delay Time	td(ON)	_	13.2	—			
Turn-On Rise Time	tR		11.7	—	ns	$\label{eq:VDD} \begin{array}{l} V_{DD}=30V, \ V_{GS}=10V, \\ I_{D}=90A, \ R_{g}=3.5\Omega \end{array}$	
Turn-Off Delay Time	t _{D(OFF)}	_	31	—			
Turn-Off Fall Time	tF	_	12	—			
Body Diode Reverse Recovery Time	trr	_	50.5	_	ns		
Body Diode Reverse Recovery Charge	Q _{RR}	_	80.8	_	nC	IF = 50A, di/dt = 100A/μs	

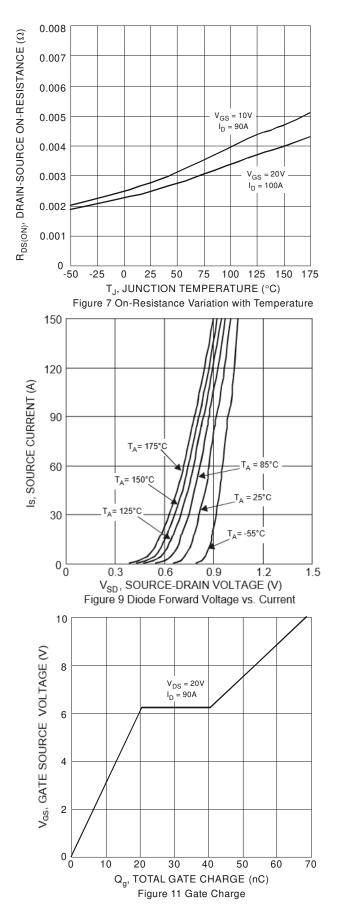
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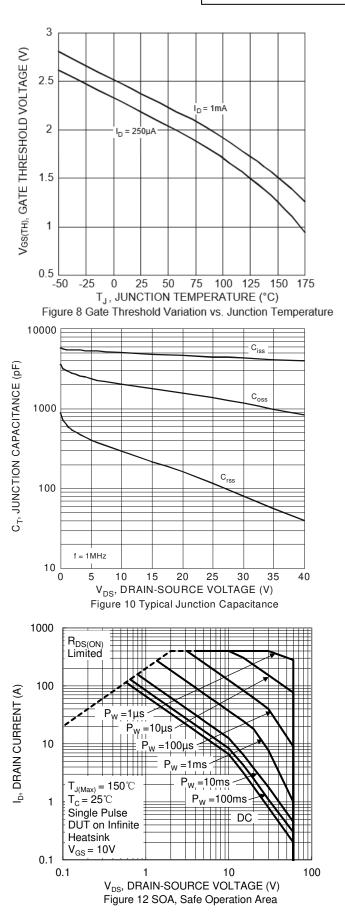






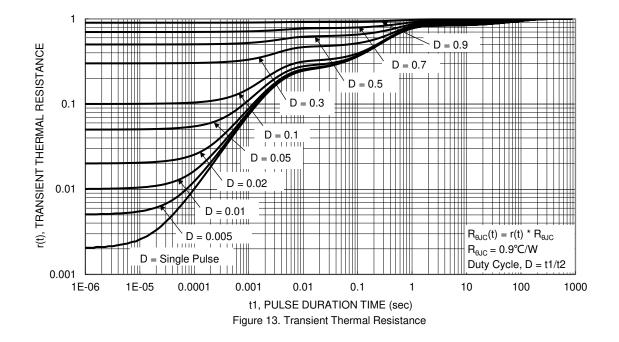






DMT6004SPS Document number: DS37324 Rev. 5 - 2



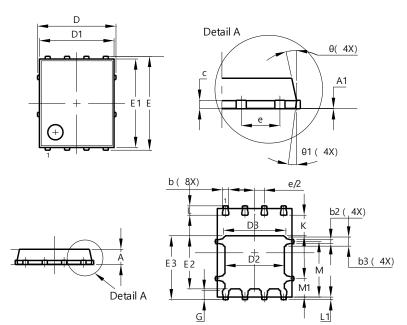




Package Outline Dimensions

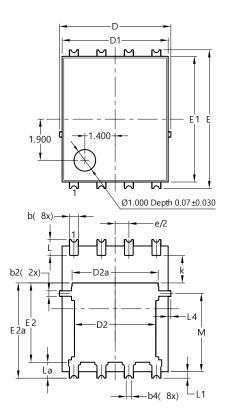
Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:



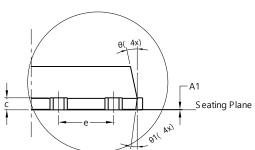
PowerDI5060-8 Тур Dim Min Max 0.90 1.10 1.00 Α **A**1 0.00 0.05 b 0.33 0.51 0.41 b2 0.200 0.350 0.273 b3 0.40 0.80 0.60 С 0.230 0.330 0.277 D 5.15 BSC D1 4.70 5.10 4.90 D2 3.70 4.10 3.90 D3 3.90 4.30 4.10 Ε 6.15 BS E1 5.60 6.00 5.80 3.28 3.48 E2 3.68 4.19 E3 3.99 4.39 1.27 BSC е 0.51 0.61 G 0.71 0.51 Κ L 0.51 0.71 0.61 L1 0.100 0.200 0.175 М 3.235 4.035 3.635 M1 1.00 1.40 1.21 Θ 10^⁰ 12º **11**⁰ Θ1 6⁰ 8⁰ 7⁰ All Dimensions in mm

Site 2:

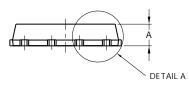


PowerDI5060-8/SWP (Type UX)

PowerDI5060-8



DETAIL A



PowerDI5060-8/SWP					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	C).25REF	-		
С	0.230	0.330	0.277		
D	-	.15 BS0	-		
D1	4.70	5.10	4.90		
D2	3.56	3.96	3.76		
D2a	3.78	4.18	3.98		
E	-	.40 BS0			
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a		4.595	4.395		
е		.27BSC)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
L1a	-	.050RE			
L4	0.025	0.225	0.125		
М	3.205	4.005	3.605		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	Dimensi	ions in	mm		

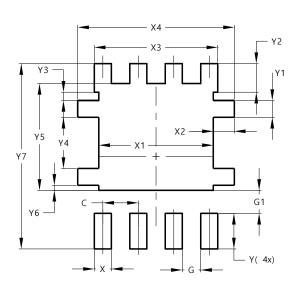
DMT6004SPS Document number: DS37324 Rev. 5 - 2



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

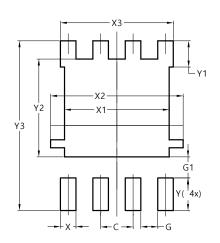


Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

PowerDI5060-8/SWP (Type UX)

PowerDI5060-8



Dimensions	Value (in mm)		
Dimensions			
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	5.190		
X3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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